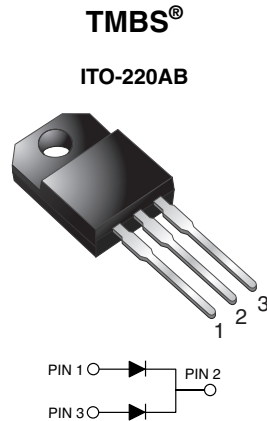




Dual Common-Cathode High Voltage Schottky Rectifier



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5.0 A
V_{RRM}	90 V, 100 V
I_{FSM}	120 A
V_F	0.75 V
T_J max.	150 °C

FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25\text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V
Working peak reverse voltage	V_{RWM}	90	100	V
Maximum DC blocking voltage	V_{DC}	90	100	V
Maximum average forward rectified current at $T_C = 105\text{ °C}$ total device per diode	$I_{F(AV)}$	10 5.0		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	120		A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$, $L = 60\text{ mH}$ per diode	E_{AS}	60		mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$, 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode	I_{RRM}	0.5		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μs
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 150		°C
Isolation voltage from terminal to heatsink with $t = 1\text{ min}$	V_{AC}	1500		V

MBRF1090CT, MBRF10100CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 5.0 A	T _C = 125 °C	V _F	0.75		V
	I _F = 5.0 A	T _C = 25 °C		0.85		
Maximum reverse current per diode at working peak reverse voltage ⁽²⁾			I _R	100		μA mA
				T _J = 25 °C T _J = 100 °C		

Notes

⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Typical thermal resistance per diode	R _{θJC}	6.8		°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	MBRF10100CT-E3/4W	1.75	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

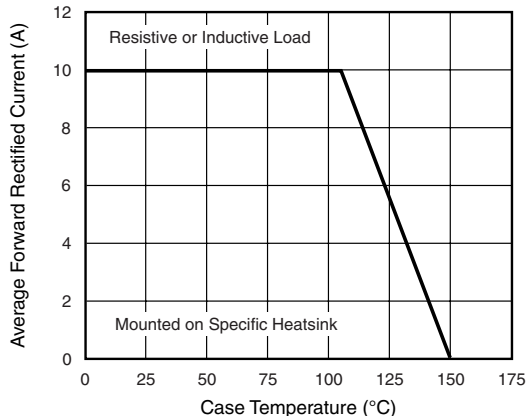


Figure 1. Forward Current Derating Curve

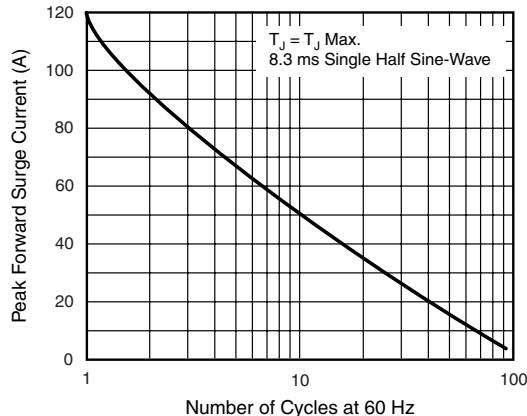


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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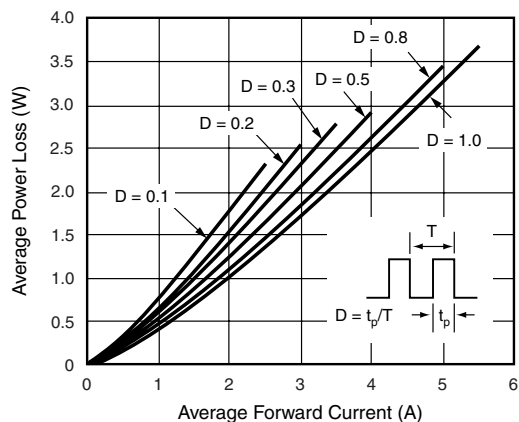


Figure 3. Forward Power Loss Characteristics Per Diode

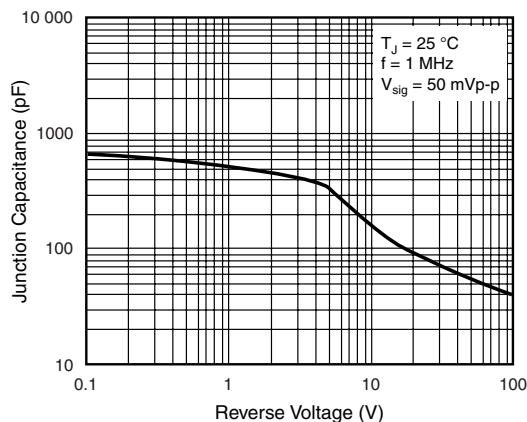


Figure 6. Typical Junction Capacitance Per Diode

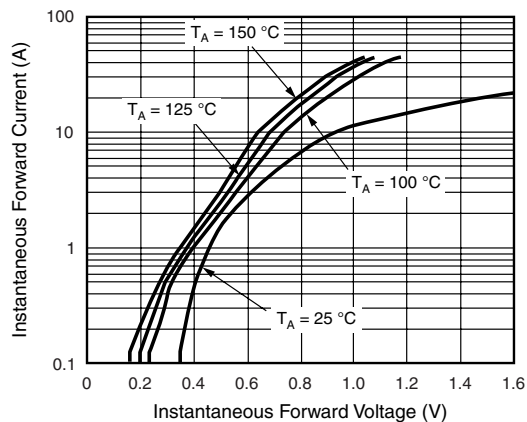


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

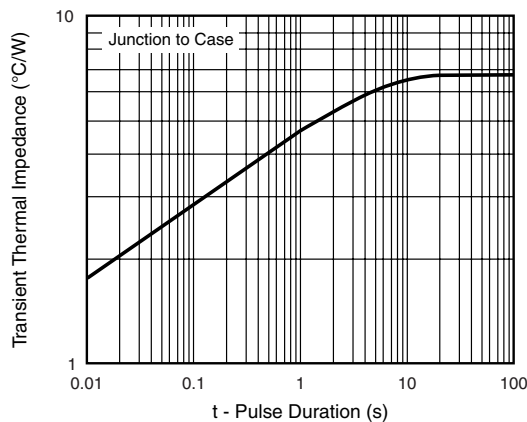


Figure 7. Typical Transient Thermal Impedance Per Diode

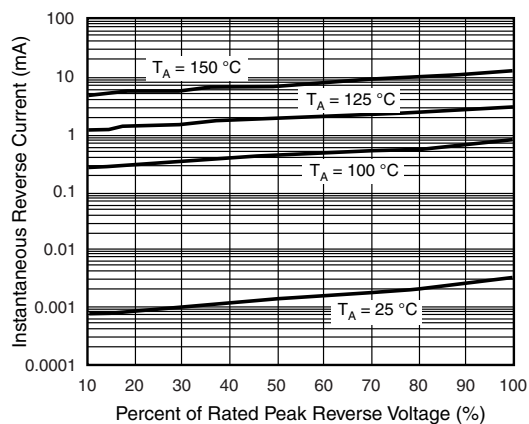


Figure 5. Typical Reverse Characteristics Per Diode

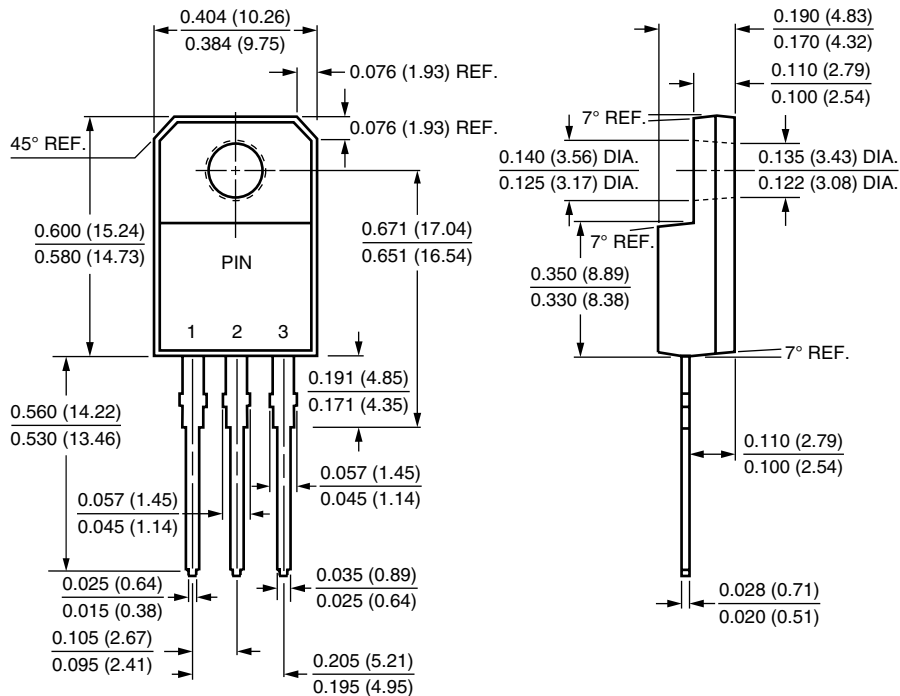
MBRF1090CT, MBRF10100CT

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB





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